

Inventor(s): Andrew J. WALKER et al. DOCKET NO.: 035905-0103

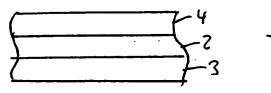


FIGURE 1

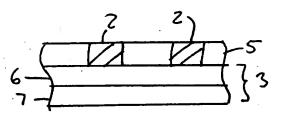


FIGURE 2A

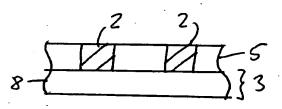


FIGURE 2B

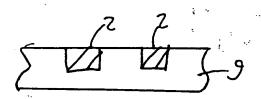


FIGURE 3

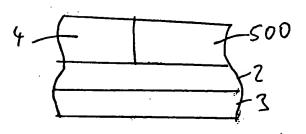


FIGURE 15

FABRICATION
Inventor(s): Andrew J. WALKER et al.
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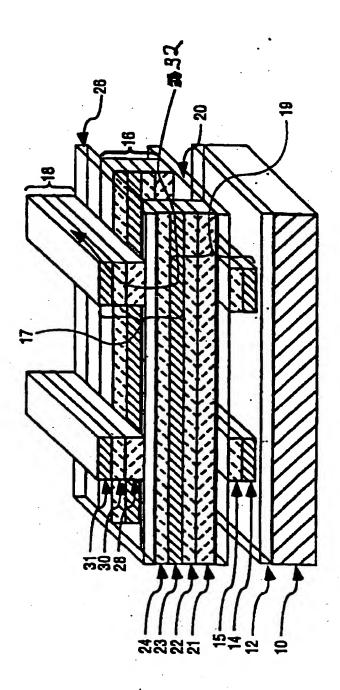


FIGURE 4A

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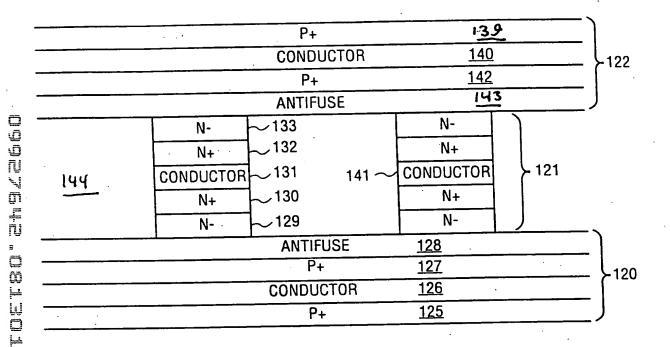
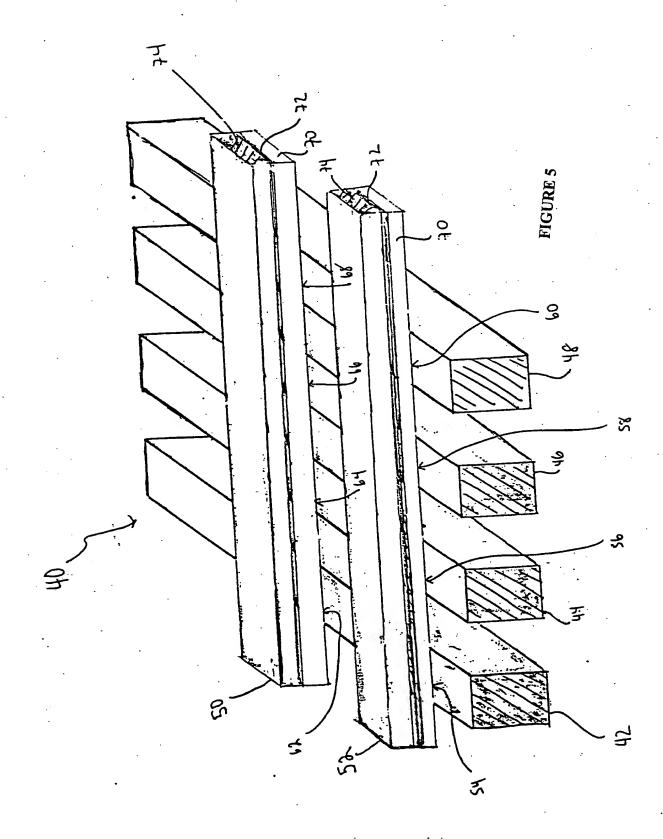


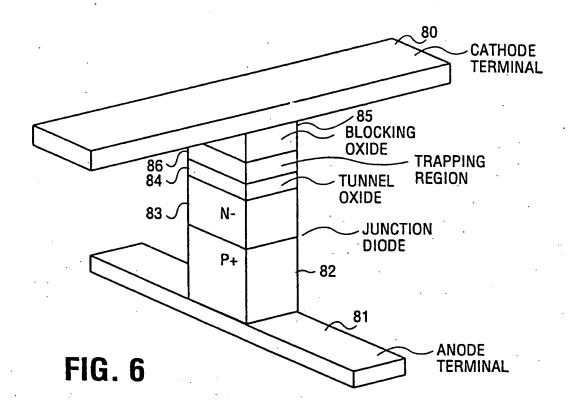
FIGURE 4B

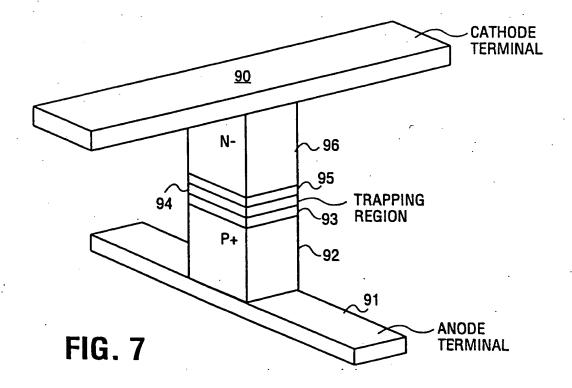


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Title: NONVOLATILE MEMORY ON SOI AND COMPOUND SEMICONDUCTOR SUBSTRATES AND METHOD OF FABRICATION Apple of the following the second of the

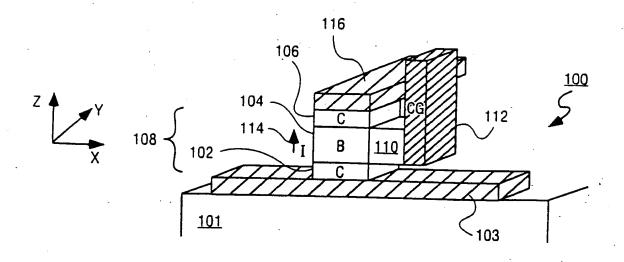
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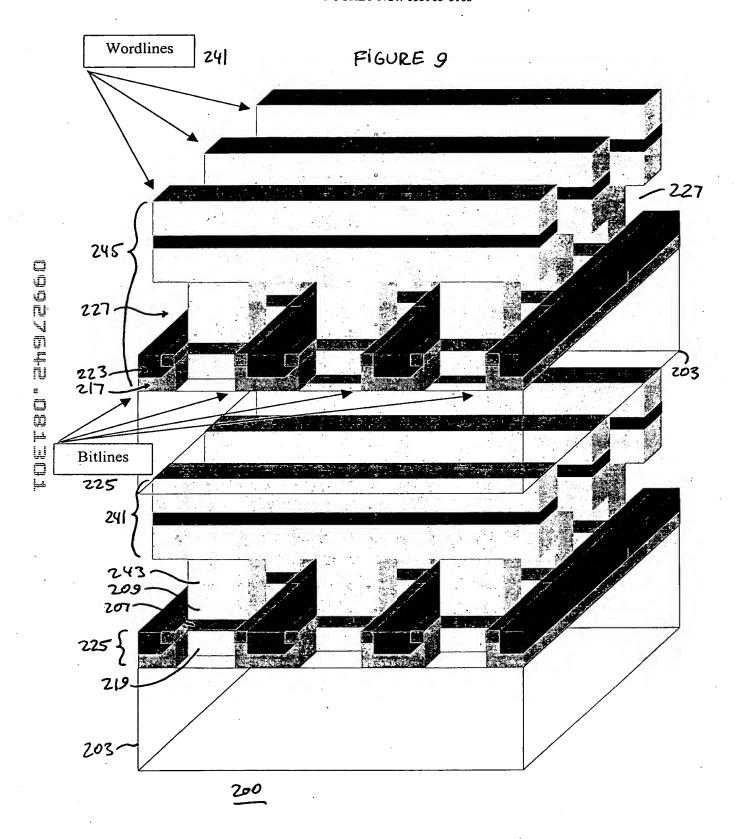




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FIGURE 8





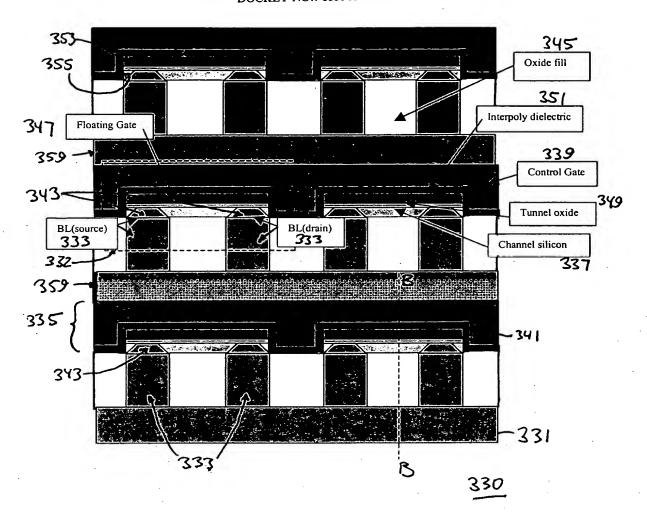


FIGURE 10A

Title: NONVOLATILE MEMORY ON SOI AND COMPOUND SEMICONDUCTOR INSTRATES AND METHOD OF FABRICATION Inventor(s): Andrew J. WALKER et al. DOCKET NO.: 035905-0103

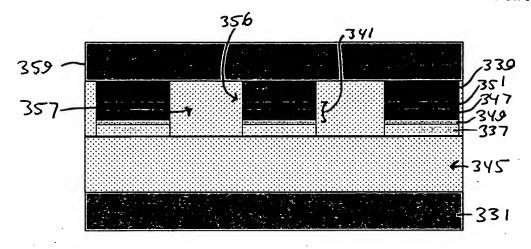
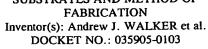
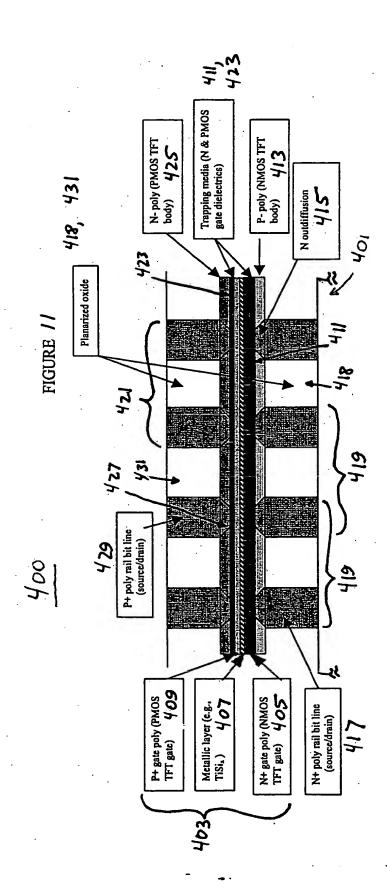
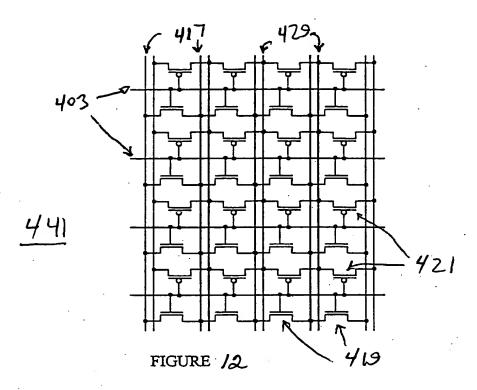
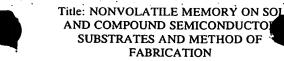


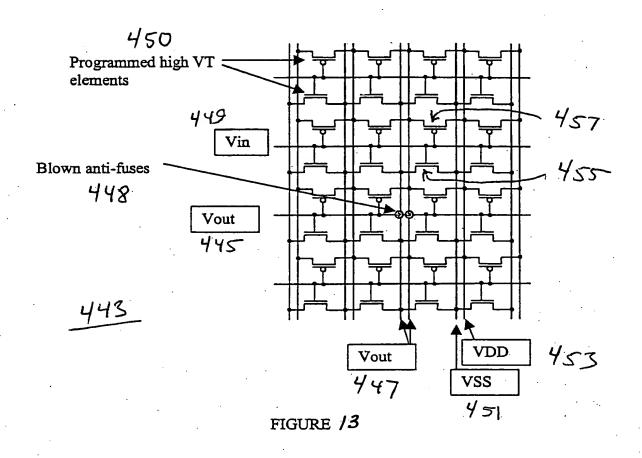
FIGURE 10B













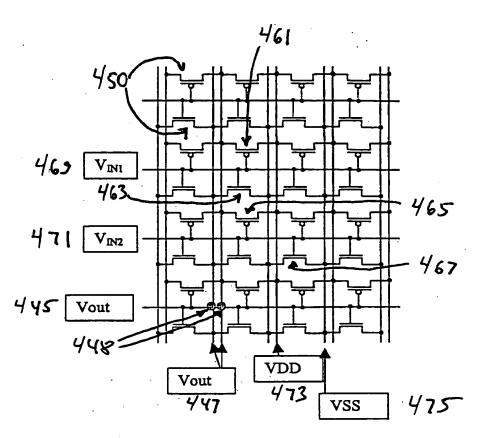


FIGURE 14